

Vishay Semiconductors

RF PIN Diodes - Dual, Common Cathode in SOT-323

Description

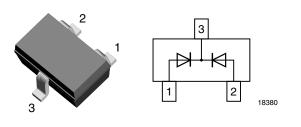
Characterized by low reverse Capacitance the PIN Diodes BAR64V-05W-V was designed for RF signal switching and tuning. As a function of the forward bias current the forward resistance (RF) can be adjusted over a wide range. A long carrier life time offers low signal distortion for signals over 10 MHz up to 3 GHz. Typical applications for these PIN Diodes are switches and attenuators in wireless, mobile and TV-systems.



- High voltage current controlled RF resistor
- Small diode capacitance
- Low series inductance
- Low forward resistance
- Improved performance due to two comiseparate dice
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Applications

- For frequencies up to 3 GHz
- RF-signal tuning
- · Signal attenuator and switches
- Mobile, wireless and TV-Applications





Mechanical Data

Case: SOT-323 Weight: approx. 5.7 mg Packaging Codes/Options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/3K per 7" reel (8 mm tape), 15K/box

Parts	Table
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Part	Ordering code	Marking	Remarks	
BAR64V-05W-V	BAR64V-05W-V BAR64V-05W-V-GS18 or BAR64V-05W-V-GS08		Tape and reel	

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Reverse voltage		V _R	100	V	
Forward current		١ _F	100	mA	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	- 55 to + 150	°C	

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Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Reverse voltage	I _R = 10 μA	V _R	100			V
Reverse current	V _R = 50 V	I _R			50	nA
Forward voltage	I _F = 50 mA	V _F			1.1	V
Diode capacitance	f = 1 MHz, V _R = 0	CD		0.5		pF
	f = 1 MHz, V _R = 1 V	CD		0.37	0.5	pF
	f = 1 MHz, V _R = 20 V	CD		0.23	0.35	pF
Forward resistance	f = 100 MHz, I _F = 1 mA	r _f		10	20	Ω
	f = 100 MHz, I _F = 10 mA	r _f		2.0	3.8	Ω
	f = 100 MHz, I _F = 100 mA	r _f		0.8	1.35	Ω
Charge carrier life time	$I_F = 10 \text{ mA}, I_R = 6 \text{ mA}, i_R = 3 \text{ mA}$	t _{rr}		1.8		μs
Series inductance		LS		1		nH

Typical Characteristics

Tamb = 25 °C, unless otherwise specified

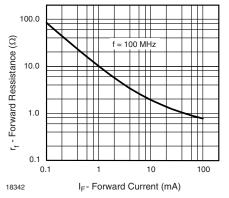


Figure 1. Forward Resistance vs. Forward Current

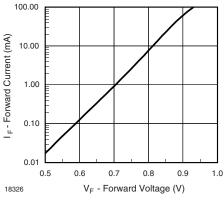


Figure 3. Forward Current vs. Forward Voltage

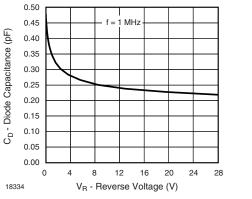


Figure 2. Diode Capacitance vs. Reverse Voltage

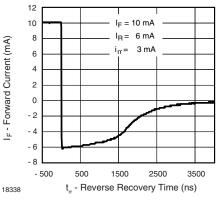


Figure 4. Typical Charge Recovery Curve



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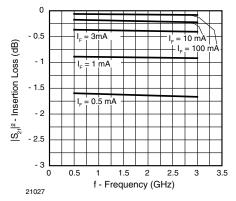


Figure 5. Insertion Loss of One Diode Inserted in Series with 50 Ω Strip Line

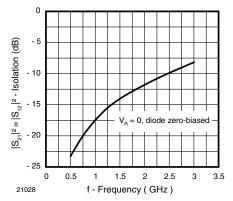


Figure 6. Isolation of One Diode Inserted in Series with 50 Ω Strip Line

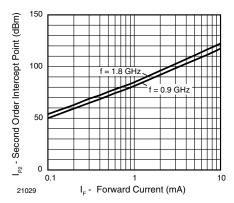


Figure 7. Second Order Intercept Point for One Diode Inserted in 50 Ω Strip Line

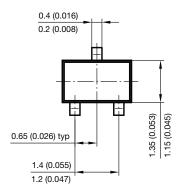
BAR64V-05W-V

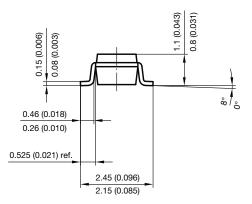


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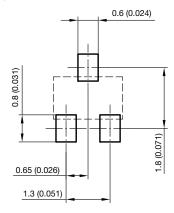
Package Dimensions in millimeters (inches): SOT-323







foot print recommendation:



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